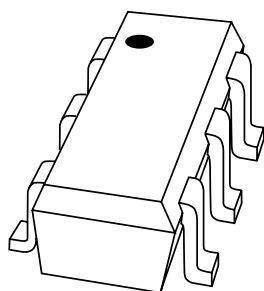


# DATA SHEET



## **PUMH9**

NPN resistor-equipped double transistor

Product specification

1999 May 06

NPN resistor-equipped double transistor

PUMH9

FEATURES

- Transistors with built-in bias resistors (R1 typ. 10 kΩ and R2 typ. 47 kΩ)
- No mutual interference between the transistors
- Simplification of circuit design
- Reduces number of components and board space.

APPLICATIONS

- Especially suitable for space reduction in interface and driver circuits
- Inverter circuit configurations without use of external resistors.

DESCRIPTION

NPN resistor-equipped double transistor in an SC-88 (SOT363) plastic package.

MARKING

| TYPE NUMBER | MARKING CODE |
|-------------|--------------|
| PUMH9       | Ht9          |

PINNING

| PIN  | DESCRIPTION |          |
|------|-------------|----------|
| 1, 4 | emitter     | TR1; TR2 |
| 2, 5 | base        | TR1; TR2 |
| 6, 3 | collector   | TR1; TR2 |

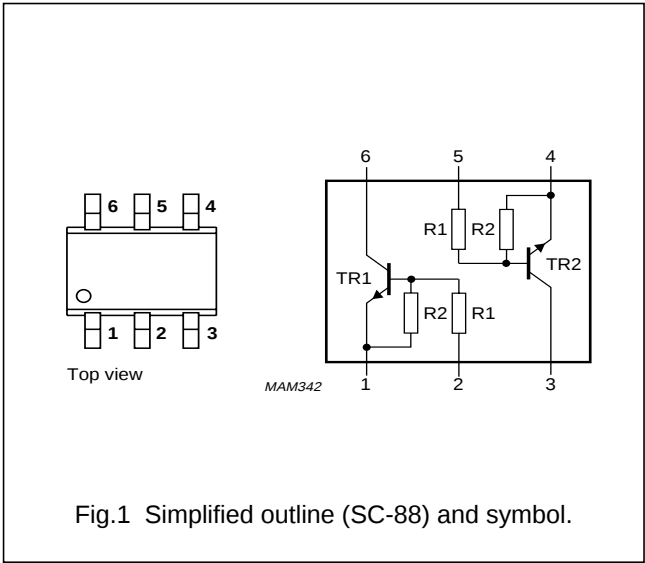


Fig.1 Simplified outline (SC-88) and symbol.

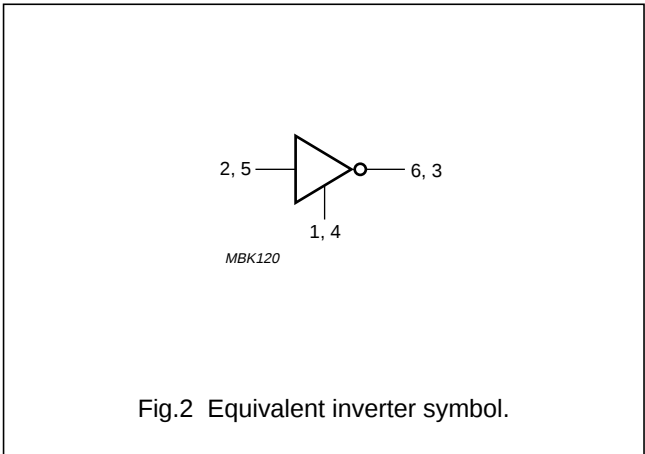


Fig.2 Equivalent inverter symbol.

## NPN resistor-equipped double transistor

## PUMH9

**LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL                | PARAMETER                     | CONDITIONS                           | MIN. | MAX. | UNIT |
|-----------------------|-------------------------------|--------------------------------------|------|------|------|
| <b>Per transistor</b> |                               |                                      |      |      |      |
| $V_{CBO}$             | collector-base voltage        | open emitter                         | –    | 50   | V    |
| $V_{CEO}$             | collector-emitter voltage     | open base                            | –    | 50   | V    |
| $V_{EBO}$             | emitter-base voltage          | open collector                       | –    | 10   | V    |
| $V_i$                 | input voltage                 |                                      | –    | +40  | V    |
|                       | positive                      |                                      |      | –10  | V    |
| $I_o$                 | output current (DC)           |                                      | –    | 100  | mA   |
| $I_{CM}$              | peak collector current        |                                      | –    | 100  | mA   |
| $P_{tot}$             | total power dissipation       | $T_{amb} \leq 25\text{ °C}$ ; note 1 | –    | 200  | mW   |
| $T_{stg}$             | storage temperature           |                                      | –65  | +150 | °C   |
| $T_j$                 | junction temperature          |                                      | –    | 150  | °C   |
| $T_{amb}$             | operating ambient temperature |                                      | –65  | +150 | °C   |
| <b>Per device</b>     |                               |                                      |      |      |      |
| $P_{tot}$             | total power dissipation       | $T_{amb} \leq 25\text{ °C}$ ; note 1 | –    | 300  | mW   |

**Note**

1. Device mounted on an FR4 printed-circuit board.

## NPN resistor-equipped double transistor

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## THERMAL CHARACTERISTICS

| SYMBOL        | PARAMETER                                   | CONDITIONS | VALUE | UNIT |
|---------------|---------------------------------------------|------------|-------|------|
| $R_{th\ j-a}$ | thermal resistance from junction to ambient | note 1     | 416   | K/W  |

## Note

1. Device mounted on an FR4 printed-circuit board.

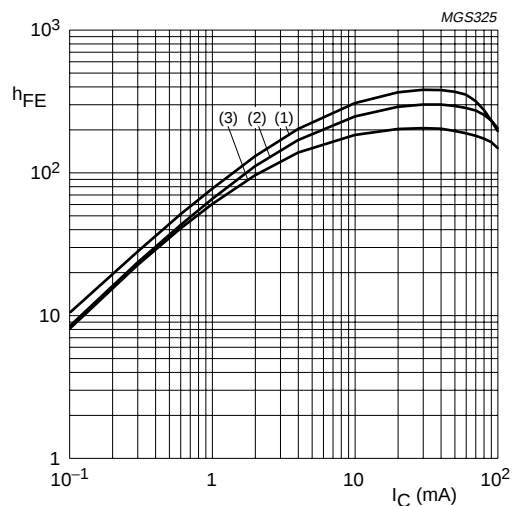
## CHARACTERISTICS

$T_{amb} = 25\text{ °C}$  unless otherwise specified.

| SYMBOL                | PARAMETER                            | CONDITIONS                                              | MIN. | TYP. | MAX. | UNIT          |
|-----------------------|--------------------------------------|---------------------------------------------------------|------|------|------|---------------|
| <b>Per transistor</b> |                                      |                                                         |      |      |      |               |
| $I_{CBO}$             | collector cut-off current            | $I_E = 0; V_{CB} = 50\text{ V}$                         | –    | –    | 100  | nA            |
| $I_{CEO}$             | collector cut-off current            | $I_B = 0; V_{CE} = 30\text{ V}$                         | –    | –    | 1    | $\mu\text{A}$ |
|                       |                                      | $I_B = 0; V_{CE} = 30\text{ V}; T_j = 150\text{ °C}$    | –    | –    | 50   | $\mu\text{A}$ |
| $I_{EBO}$             | emitter cut-off current              | $I_C = 0; V_{EB} = 5\text{ V}$                          | –    | –    | 150  | $\mu\text{A}$ |
| $h_{FE}$              | DC current gain                      | $I_C = 5\text{ mA}; V_{CE} = 5\text{ V}$                | 100  | –    | –    |               |
| $V_{CEsat}$           | collector-emitter saturation voltage | $I_C = 10\text{ mA}; I_B = 0.25\text{ mA}$              | –    | –    | 100  | mV            |
| $V_{i(off)}$          | input-off voltage                    | $I_C = 100\text{ }\mu\text{A}; V_{CE} = 5\text{ V}$     | –    | 0.7  | 0.5  | V             |
| $V_{i(on)}$           | input-on voltage                     | $I_C = 1\text{ mA}; V_{CE} = 0.3\text{ V}$              | 1.4  | 0.8  | –    | V             |
| R1                    | input resistor                       |                                                         | 7    | 10   | 13   | k $\Omega$    |
| $\frac{R2}{R1}$       | resistor ratio                       |                                                         | 3.7  | 4.7  | 5.7  |               |
| $C_c$                 | collector capacitance                | $I_E = I_e = 0; V_{CB} = 10\text{ V}; f = 1\text{ MHz}$ | –    | –    | 2.5  | pF            |

## NPN resistor-equipped double transistor

## PUMH9



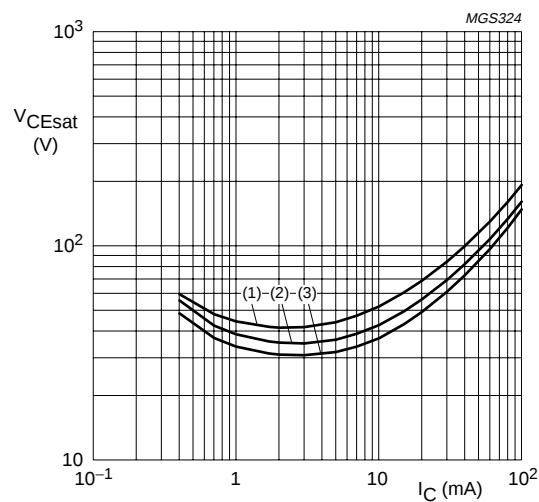
$V_{CE} = 5\text{ V}$ .

(1)  $T_{amb} = 100^\circ\text{C}$ .

(2)  $T_{amb} = 25^\circ\text{C}$ .

(3)  $T_{amb} = -40^\circ\text{C}$ .

Fig.3 DC current gain as a function of collector current; typical values.



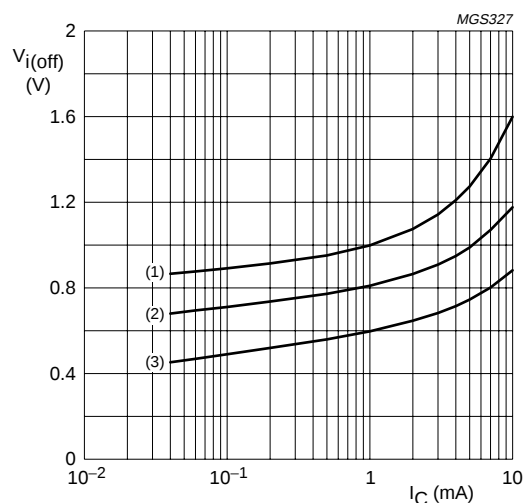
$I_C/I_B = 20$ .

(1)  $T_{amb} = 100^\circ\text{C}$ .

(2)  $T_{amb} = 25^\circ\text{C}$ .

(3)  $T_{amb} = -40^\circ\text{C}$ .

Fig.4 Collector-emitter saturation voltage as a function of collector current; typical values.



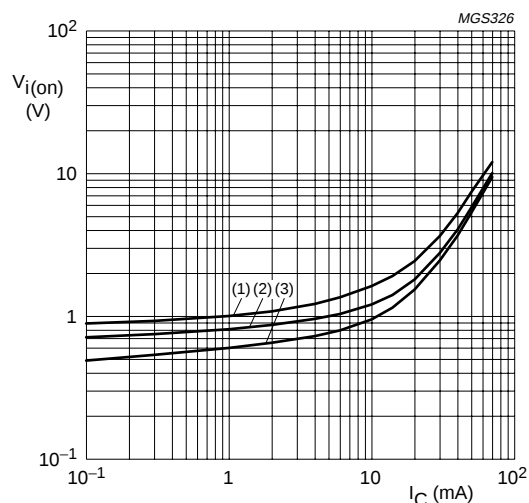
$V_{CE} = 5\text{ V}$ .

(1)  $T_{amb} = -40^\circ\text{C}$ .

(2)  $T_{amb} = 25^\circ\text{C}$ .

(3)  $T_{amb} = 100^\circ\text{C}$ .

Fig.5 Input-off voltage as a function of collector current; typical values.



$V_{CE} = 0.3\text{ V}$ .

(1)  $T_{amb} = -40^\circ\text{C}$ .

(2)  $T_{amb} = 25^\circ\text{C}$ .

(3)  $T_{amb} = 100^\circ\text{C}$ .

Fig.6 Input-on voltage as a function of collector current; typical values.

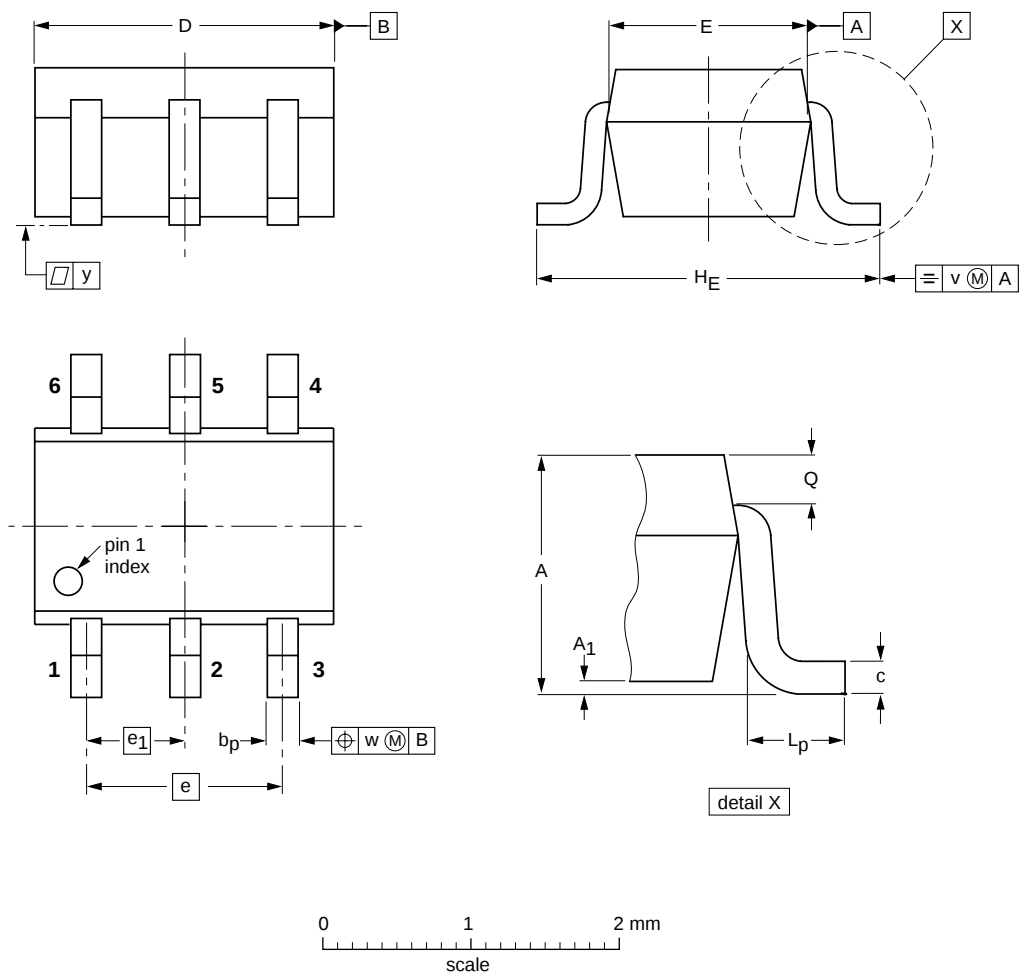
NPN resistor-equipped double transistor

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PACKAGE OUTLINE

Plastic surface mounted package; 6 leads

SOT363



DIMENSIONS (mm are the original dimensions)

| UNIT | A          | A1<br>max | bp           | c            | D          | E            | e   | e1   | HE         | Lp           | Q            | v   | w   | y   |
|------|------------|-----------|--------------|--------------|------------|--------------|-----|------|------------|--------------|--------------|-----|-----|-----|
| mm   | 1.1<br>0.8 | 0.1       | 0.30<br>0.20 | 0.25<br>0.10 | 2.2<br>1.8 | 1.35<br>1.15 | 1.3 | 0.65 | 2.2<br>2.0 | 0.45<br>0.15 | 0.25<br>0.15 | 0.2 | 0.2 | 0.1 |

| OUTLINE<br>VERSION | REFERENCES |       |       |  | EUROPEAN<br>PROJECTION | ISSUE DATE |
|--------------------|------------|-------|-------|--|------------------------|------------|
|                    | IEC        | JEDEC | EIAJ  |  |                        |            |
| SOT363             |            |       | SC-88 |  |                        | 97-02-28   |

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NPN resistor-equipped double transistor

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PUMH9

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**DEFINITIONS**

| <b>Data sheet status</b>                                                                                                                                                                                                                                                                                                                                                                                                                                  |                                                                                       |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------|
| Objective specification                                                                                                                                                                                                                                                                                                                                                                                                                                   | This data sheet contains target or goal specifications for product development.       |
| Preliminary specification                                                                                                                                                                                                                                                                                                                                                                                                                                 | This data sheet contains preliminary data; supplementary data may be published later. |
| Product specification                                                                                                                                                                                                                                                                                                                                                                                                                                     | This data sheet contains final product specifications.                                |
| <b>Limiting values</b>                                                                                                                                                                                                                                                                                                                                                                                                                                    |                                                                                       |
| Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability. |                                                                                       |
| <b>Application information</b>                                                                                                                                                                                                                                                                                                                                                                                                                            |                                                                                       |
| Where application information is given, it is advisory and does not form part of the specification.                                                                                                                                                                                                                                                                                                                                                       |                                                                                       |

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